

QSI LASER DIODE

SPECIFICATIONS FOR APPROVAL

Tentative

Customer :

Model : QL65D5S-A/B/C-L

Signature of Approval

Approved by _____

Checked by _____

Issued by _____

Approval by Customer



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QL65D5S-A/B/C-L

InGaAIP Laser Diode

Quantum Semiconductor International Co., Ltd.

APR. 2015

◆ OVERVIEW

QL65D5S-A/B/C-L is a MOCVD grown 650nm band *InGaAIP* laser diode with quantum well structure. It's an attractive light source, with a typical light output power of 5mW for optoelectronic devices such as Laser Pointer & Bar Code Reader

◆ APPLICATION

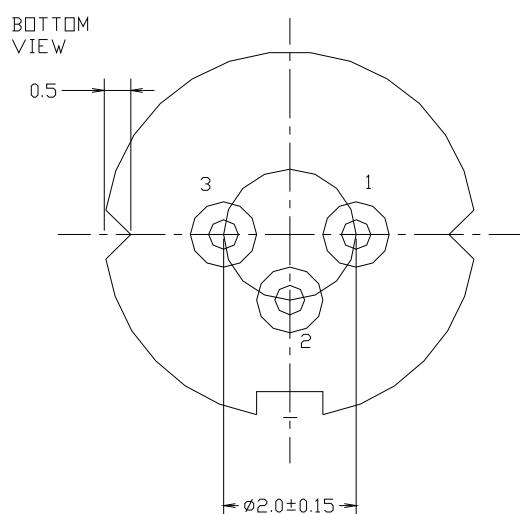
- Laser Pointer
- Optical Leveler
- Bar Code Reader

◆ FEATURES

- Visible Light Output : $\lambda_p = 650$ nm
- Optical Power Output : 5mW CW
- Package Type : TO-18 (5.6mm ϕ)
- Built-in Photo Diode for Monitoring Laser Diode

◆ ELECTRICAL CONNECTION

Bottom View



Pin Configuration

A	LD cathode, PD anode (Fig. 1)
B	LD , PD anode (Fig. 2)
C	LD anode, PD cathode (Fig. 3)

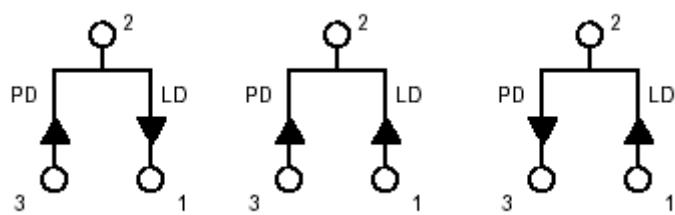


Fig. 1
QL65D5SA-L

Fig. 2
QL65D5SB-L

Fig. 3
QL65D5SC-L

◆ ABSOLUTE MAXIMUM RATING at Tc=25°C

Items	Symbols	Values	Unit
Optical Output Power	P	7	mW
Laser Diode Reverse Voltage	V	2	V
Photo Diode Reverse Voltage	V	30	V
Operating Temperature	Topr	-10 ~ +50	°C
Storage Temperature	Tstg	-40 ~ +85	°C

◆ ELECTRICAL and OPTICAL CHARACTERISTICS at Tc=25°C

Items	Symbols	Min.	Typ.	Max.	Unit	Condition
Optical Output Power	Po	-	5	-	mW	-
Threshold Current	Ith	-	8	12	mA	-
Operating Current	Iop	-	15	22	mA	Po=5mW
Slope Efficiency	SE	0.5	0.65	1.0	mW/mA	3~5mW
Operating Voltage	Vop	-	2.3	2.6	V	Po=5mW
Lasing Wavelength	λp	648	655	660	nm	Po=5mW
Beam Divergence	θ	6	8.5	12	deg	Po=5mW
	θ ⊥	22	36	45	deg	Po=5mW
Beam Angle	Δθ	-3	-	3	deg	Po=5mW
	Δθ ⊥	-3	-	3	deg	Po=5mW
Monitor Current	Im	0.1	0.3	0.5	mA	Po=5mW
Optical Distance	ΔX, ΔY, ΔZ	-	-	±60	μm	-

NOTICE : QL65D5S-A/B/C-L to be operated on APC

The above product specifications are subject to change without notice.

